

**IN THE CLAIMS**

1. (Previously Amended) A light-emitting device comprising a layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75%, said anode has a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Zr, Nb, Mo, and W, and said anode comprises a first layer comprising a first compound selected from the group consisting of zinc, indium, and tin and a second layer comprising said metal.

2. (Original) A light-emitting device according to Claim 1, wherein the visible light has a wavelength ranging from 380 nm to 780 nm.

3. (Previously Amended) A light-emitting device according to Claim 1, wherein said anode comprises a first layer comprising a first compound selected from the group consisting of zinc, indium, and tin and a second layer comprising said metal.

4. (Withdrawn).

5. (Previously Amended) A light-emitting device according to Claim 1, wherein said second layer comprises a metal compound having said metal and a material selected from the group consisting of oxides, nitrides and oxide-nitrides.

6. (Withdrawn).

7. (Original) A light-emitting device according to Claim 1, wherein said anode has a work function of 3.0 to 7.0 eV.

8. (Previously Amended) A light-emitting device according to Claim 1, wherein said device comprises, on a transparent substrate, a built-up body including said anode, an organic layer containing said emission region and said cathode.

9. (Original) A light-emitting device according to Claim 8, wherein said organic layer includes a hole transport layer at a side of said anode and an electron transport layer at a side of said cathode.

10. (Original) A light-emitting device according to Claim 9, wherein said organic layer further comprises a hole injection layer between said anode and said hole transport layer.

11. (Original) A light-emitting device according to Claim 9, wherein said organic layer has an emission layer between said hole transport layer and said electron transport layer.

12. (Currently Amended) An electronic device comprising the light-emitting device of Claim 1, wherein the electronic device is one of a display, a computer, a television set, a billboard, a studio screen, a facsimile, a portable telephone, a portable terminal, a vehicle and an acoustic device.

13. (Previously Added) A light-emitting device according to Claim 1, where said anode has a dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

14. (Previously Amended) A light-emitting device comprising:

a layer including an emission region;

an anode; and

a cathode, wherein said layer is disposed between said anode and said cathode, and

said anode has a visible light transmittance of 35 to 75%, a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Ti, Zr, Nb, Mo, and W, and a dopant material selected from the group consisting of  $R_xNiO$ ,  $R_xWO_3$ , and  $TiNb_xO_y$ , wherein R is selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

15. (Previously Amended) A light-emitting device according to Claim 1, where said second layer has a thickness in the range of 15 nm to 80 nm.

16. (Previously Added) A light-emitting device according to Claim 15, where said light-emitting device has a luminance that increases within the range of 620 to 1200 cd/m<sup>2</sup> as said thickness of said second layer is decreased within the range of 15 nm to 80 nm and has a contrast corresponding to said luminance that increases within the range of 250:1 to 410:1 as said thickness of said second layer is decreased within the range of 15 nm to 80 nm.

17. (Previously Amended) A light-emitting device comprising an inorganic layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75% wherein said anode comprises a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Ti, Zr, Nb, Mo, and W and said anode has a dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

18. (Previously Added) A light-emitting device according to Claim 17, wherein the visible light has a wavelength ranging from 380 nm to 780 nm.

19. (Withdrawn).

20. (Previously Amended) A light emitting device according to claim 17, wherein said anode comprises a metal compound having said metal and a material selected from the group consisting of oxides, nitrides and oxide-nitrides.

21. (Previously Amended) A light emitting device according to claim 17, wherein said anode comprises a plurality of layers, a first set of the layers having a material selected from the group comprising of zinc, indium or tin, a second of the layers having said material.

22. (Withdrawn).

23. (Previously Added) A light-emitting device according to Claim 17, wherein said anode has a work function of 3.0 to 7.0 eV.

24. (Previously Amended) A light-emitting device comprising a layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75%, a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Ti, Zr, Nb, Mo, and W, and a first layer comprising a first compound selected from the group consisting of zinc, indium, and tin and a second layer comprising said metal, and wherein said second layer has a thickness that is greater than 20 nm and less than or equal to 80 nm, the anode further including dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.